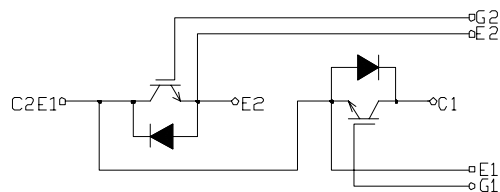


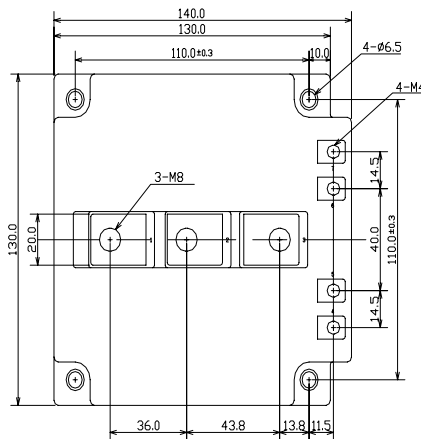
## IGBT MODULE Dual 600A 1200V

## PDMB600B12

## CIRCUIT



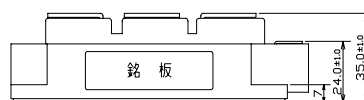
## OUTLINE DRAWING



4-fasten- tab No 110

Dimension(mm)

Approximate Weight : 1,200g



## MAXMUM RATINGS (Tc=25°C)

| Item                                           |                           | Symbol           | PDMB600B12  |      | Unit |
|------------------------------------------------|---------------------------|------------------|-------------|------|------|
| Collector-Emitter Voltage                      |                           | V <sub>CES</sub> | 1200        |      | V    |
| Gate - Emitter Voltage                         |                           | V <sub>GES</sub> | +/- 20      |      | V    |
| Collector Current                              | DC                        | I <sub>C</sub>   | 600         |      | A    |
|                                                | 1 ms                      | I <sub>CP</sub>  | 1200        |      |      |
| Collector Power Dissipation                    |                           | P <sub>C</sub>   | 2770        |      | W    |
| Junction Temperature Range                     |                           | T <sub>j</sub>   | -40 to +150 |      | °C   |
| Storage Temperature Range                      |                           | T <sub>stg</sub> | -40 to +125 |      | °C   |
| Isolation Voltage Terminal to Base AC, 1 min.) |                           | V <sub>ISO</sub> | 2500        |      | V    |
| Mounting Torque                                | Module Base to Heat sink  | F <sub>TOR</sub> | 3           |      | N•m  |
|                                                | Bus Bar to Main Terminals |                  | M4          | 1.4  |      |
|                                                |                           |                  | M8          | 10.5 |      |

## ELECTRICAL CHARACTERISTICS (Tc=25°C)

| Characteristic                       |               | Symbol        | Test Condition                                                              | Min. | Typ.  | Max. | Unit |
|--------------------------------------|---------------|---------------|-----------------------------------------------------------------------------|------|-------|------|------|
| Collector-Emitter Cut-Off Current    |               | $I_{CES}$     | $V_{CE}=1200V, V_{GE}=0V$                                                   | -    | -     | 12   | mA   |
| Gate-Emitter Leakage Current         |               | $I_{GES}$     | $V_{GE}=+/- 20V, V_{CE}=0V$                                                 | -    | -     | 1.0  | μA   |
| Collector-Emitter Saturation Voltage |               | $V_{CE(sat)}$ | $I_C=600A, V_{GE}=15V$                                                      | -    | 1.9   | 2.4  | V    |
| Gate-Emitter Threshold Voltage       |               | $V_{GE(th)}$  | $V_{CE}=5V, I_C=600mA$                                                      | 4.0  | -     | 8.0  | V    |
| Input Capacitance                    |               | $C_{ies}$     | $V_{CE}=10V, V_{GE}=0V, f=1MHz$                                             | -    | 50000 | -    | pF   |
| Switching Time                       | Rise Time     | $t_r$         | $V_{CC}=600V$<br>$R_L=1\text{ohm}$<br>$R_G=1\text{ohm}$<br>$V_{GE}=+/- 15V$ | -    | 0.25  | 0.45 | μs   |
|                                      | Turn-on Time  | $t_{on}$      |                                                                             | -    | 0.40  | 0.70 |      |
|                                      | Fall Time     | $t_f$         |                                                                             | -    | 0.25  | 0.35 |      |
|                                      | Turn-off Time | $t_{off}$     |                                                                             | -    | 0.80  | 1.10 |      |

## FREE WHEELING DIODES RATINGS &amp; CHARACTERISTICS (Tc=25°C)

| FREE-WHEELING DIODE RATINGS & CHARACTERISTICS (Tc = 25°C) |      |                 |             |      |
|-----------------------------------------------------------|------|-----------------|-------------|------|
| Item                                                      |      | Symbol          | Rated Value | Unit |
| Forward Current                                           | DC   | I <sub>F</sub>  | 600         | A    |
|                                                           | 1 ms | I <sub>FM</sub> | 1200        |      |

| Characteristic        | Symbol   | Test Condition                             | Min. | Typ. | Max. | Unit |
|-----------------------|----------|--------------------------------------------|------|------|------|------|
| Peak Forward Voltage  | $V_F$    | $I_F=600A, V_{GE}=0V$                      | -    | 1.9  | 2.4  | V    |
| Reverse Recovery Time | $t_{rr}$ | $I_F=600A, V_{GE}=-10V, di/dt=1200A/\mu s$ | -    | 0.25 | 0.35 | μs   |

## THERMAL CHARACTERISTICS

| Characteristic    |       | Symbol        | Test Condition   | Min. | Typ. | Max.  | Unit |
|-------------------|-------|---------------|------------------|------|------|-------|------|
| Thermal Impedance | IGBT  | $R_{th(j-c)}$ | Junction to Case | -    | -    | 0.044 | °C/W |
|                   | DIODE |               |                  | -    | -    | 0.035 |      |

## PDMB600B12

Fig.1- Output Characteristics (Typical)

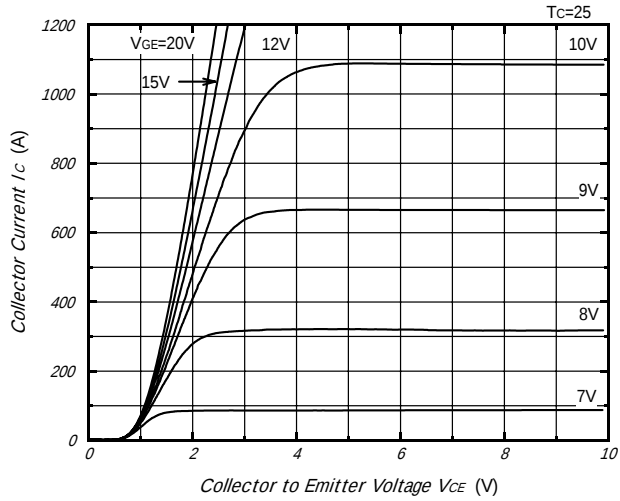


Fig.2- Collector to Emitter On Voltage vs. Gate to Emitter Voltage (Typical)

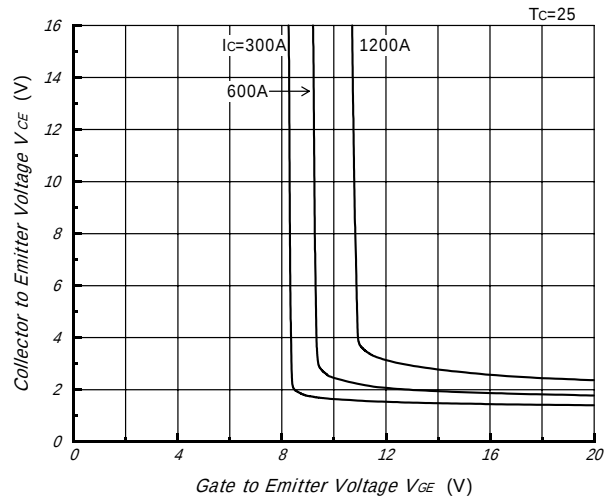


Fig.3- Collector to Emitter On Voltage vs. Gate to Emitter Voltage (Typical)

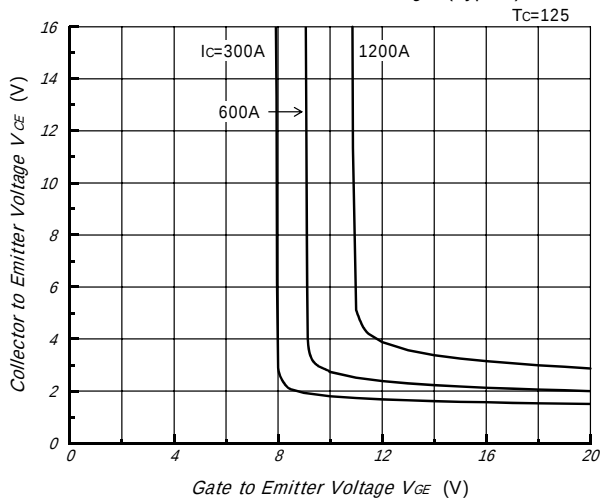


Fig.4- Gate Charge vs. Collector to Emitter Voltage (Typical)

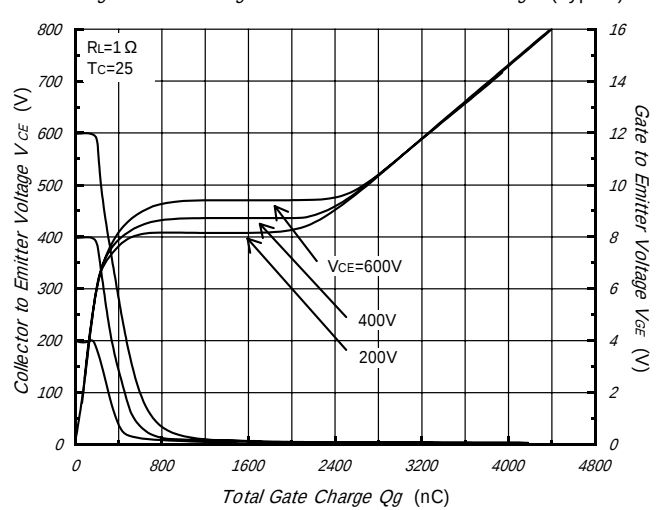


Fig.5- Capacitance vs. Collector to Emitter Voltage (Typical)

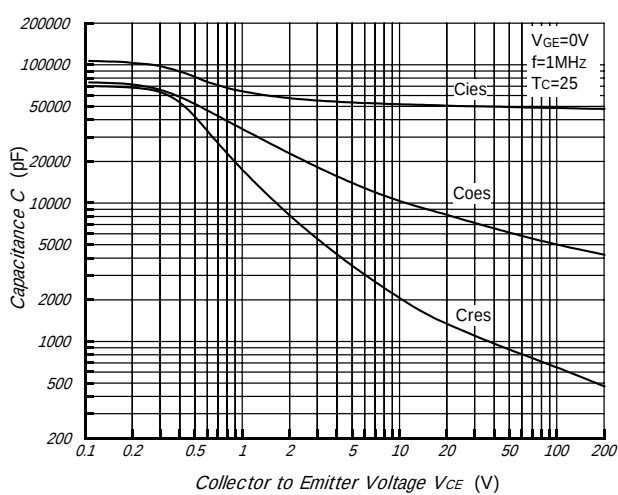
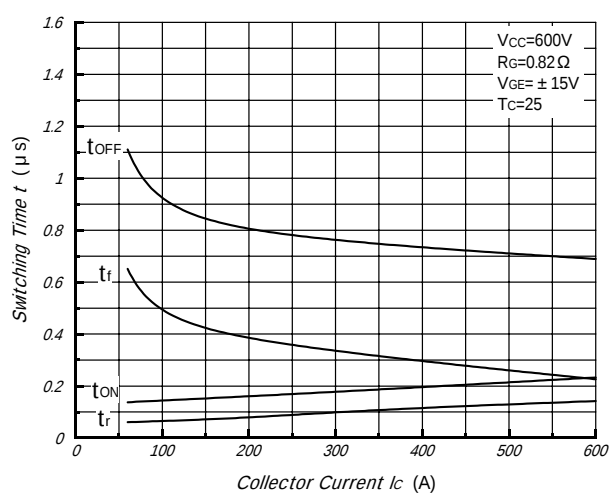


Fig.6- Collector Current vs. Switching Time (Typical)



## PDMB600B12

Fig.7- Series Gate Impedance vs. Switching Time (Typical)

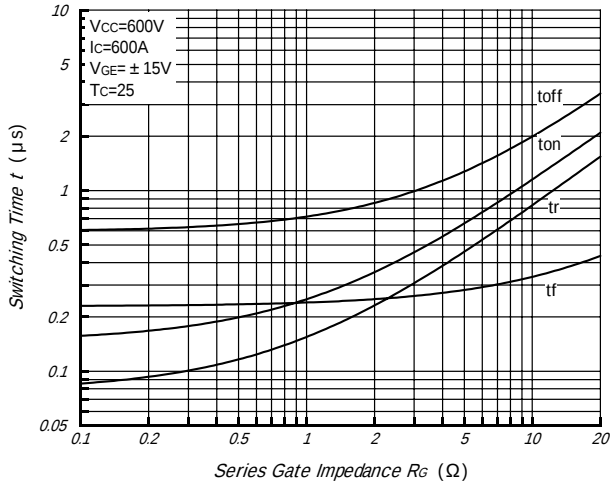


Fig.8- Forward Characteristics of Free Wheeling Diode (Typical)

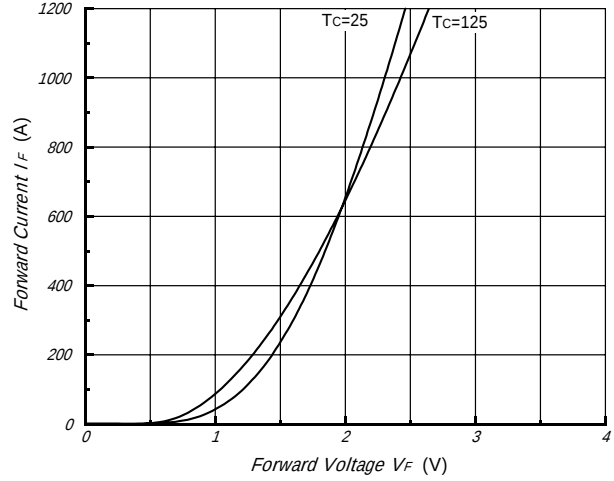


Fig.9- Reverse Recovery Characteristics (Typical)

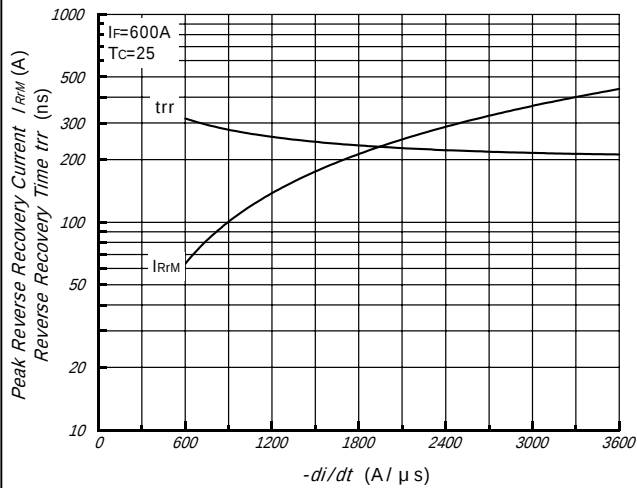


Fig.10- Reverse Bias Safe Operating Area (Typical)

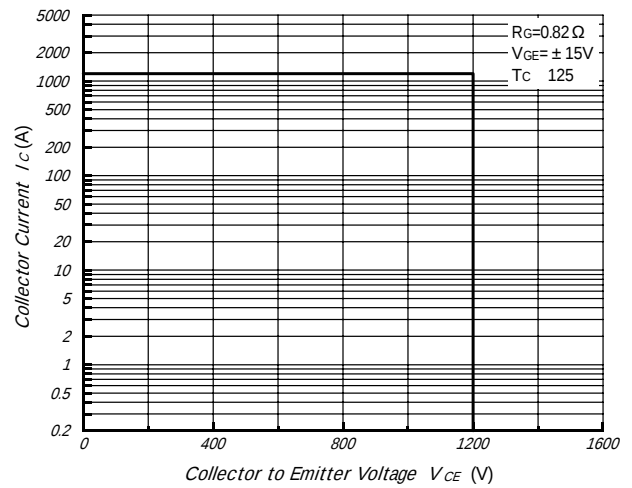


Fig.11- Transient Thermal Impedance

